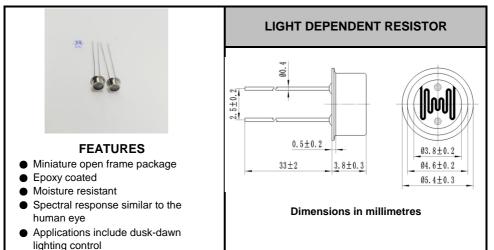


## 晶创和立科技 GL4510F



## SPECIFICATION AND PERFORMANCE

Mc	Model	Vmax (VDC)	Pmax (mW)	Ambient temp(℃)	Spectral peak (nm)	Light Resistance at 10Lux (KΩ)	Dark Resistance (MΩ)	Gamm a value at 100- 10Lux	Response Lime (ms)	
IVIC									Rise Time	Decay time
GL4	510F	100	50	-30~+70	540	8-20	1	0.75	30	30

## **Measuring Conditions**

## KΩ 1. Light resistance: **Spectral Response** 1000 Measured at 10 Lux with standard light A (2854K color temperature) and 2hr Relative Sensitivity (%) illumination at 400-600 lux prior to testing. 100 2. Dark Resistance: 100 Measured 10 senconds after closed 10 lux. 80 3. Gamma Characteristic: Between 10 lux ande 100 lux and given by 60 $\gamma = \lg(R10/R100)$ R10、R100 Cell resistance at 10 lux and 10 40 100 lux. The error of $\gamma$ is $\pm 0.1$ . 20 4. Pmax: Max. power dissipation at ambient temperature of 25 °C. 0 400 500 600 700 800 900 1000 10 100lux 5. Vmax: 1 Max. voltage in darkness that may be Wavelength (nm) applied to the cell continuously.

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